

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>ES2F-M3/5BT</u>

For any questions, you can email us directly: sales@integrated-circuit.com



www.vishay.com

ES2F-M3, ES2G-M3

HALOGEN

FREE

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AA (SMB)

Λ٦	ГІІ	

- · Glass passivated pellet chip junction
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** Color band denotes cathode end

PRIMARY CHARACTERISTICS				
2.0 A				
300 V, 400 V				
50 A				
35 ns				
1.1 V				
150 °C				
DO-214AA (SMB)				
Single die				

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ES2F	ES2G	UNIT		
Device marking code		EF	EG			
Maximum repetitive peak reverse voltage	V_{RRM}	300	400	V		
Working peak reverse voltage	V_{RWM}	225	300	V		
Maximum RMS voltage	V _{RMS}	210	280	V		
Maximum average forward rectified current at T _L = 110 °C	I _{F(AV)}	2.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50		Α		
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150		°C		



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Datasheet of ES2F-M3/5BT - DIODE GEN PURP 300V 2A DO214AA

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	ES2F	ES2G	UNIT
Maximum instantaneous forward voltage	2.0 A		V _F ⁽¹⁾	1.	1	V
Maximum reverse current at V _{RRM}		T _A = 25 °C		10 200		μΑ
		T _A = 100 °C	IR			
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	35		ns
Maximum reverse recovery time	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	50		ns
Maximum reverse recovery current	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		I _{RM}	3.0		Α
Maximum stored charge	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		Q _{rr}	50		nC
Typical junction capacitance	4.0 V, 1 MHz		CJ	1:	5	pF

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	BOL ES2F ES2G		UNIT		
Maximum thermal resistance	R _{0JA} (1)	75		°C/W		
Maximum mermanesistance	R _{0JL} (1)	25		C/VV		

Note

 $^{^{(1)}\,}$ Units mounted on PCB 5.0 mm x 5.0 mm (0.013 mm thick) land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ES2G-M3/52T	0.096	52T	750	7" diameter plastic tape and reel		
ES2G-M3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel		



ES2F-M3, ES2G-M3

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

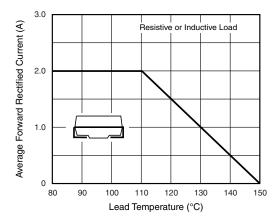


Fig. 1 - Maximum Forward Current Derating Curve

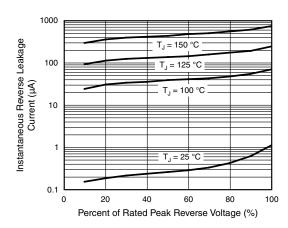


Fig. 4 - Typical Reverse Leakage Characteristics

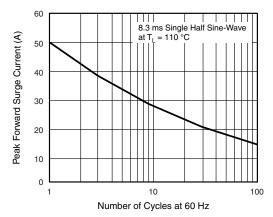


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

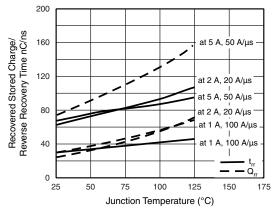


Fig. 5 - Reverse Switching Characteristics

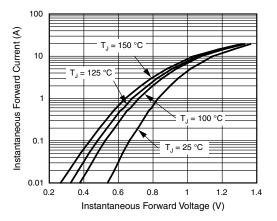


Fig. 3 - Typical Instantaneous Forward Characteristics

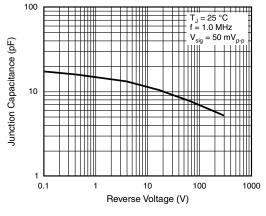


Fig. 6 - Typical Junction Capacitance



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Datasheet of ES2F-M3/5BT - DIODE GEN PURP 300V 2A DO214AA

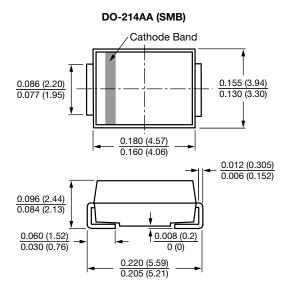
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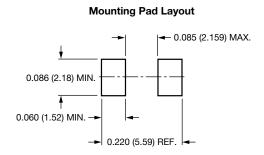


ES2F-M3, ES2G-M3

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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